PESD7V0L1BSLAZ
ESD PROTECTION DIODE

Discription

Low capacitance bidirectional ElectroStatic Discharge (ESD) protection diode in a DFN1006(SOD-882) leadless ultra small Surface-Mounted Device (SMD) plastic package designed to protect one signal line from the damage caused by ESD and other transients.



DFN1006-2L

Features

★ Bidirectional ESD protection of one line
★ Low operating voltage: 7.0 V
★ Low clamping voltage VC = 13V @8A
★ Response time is typically<1ns
★ Ultra Low Leakage:nALevel
★ IEC 61000-4-2: level 4 (ESD)
★ IEC 61000-4-5 (surge): IPPMQ 8A



Circuit Diagram

Applications

★ Portable electronics
★ Computers and peripherals
★ Audio and video equipment
★ Cellular handsets and accessories
★ Communication systems
★ Power supplies

Ordering information

Product ID	Pack	Qty(PCS)
PESD7V0L1BSLAZ	DFN1006-2L	10000

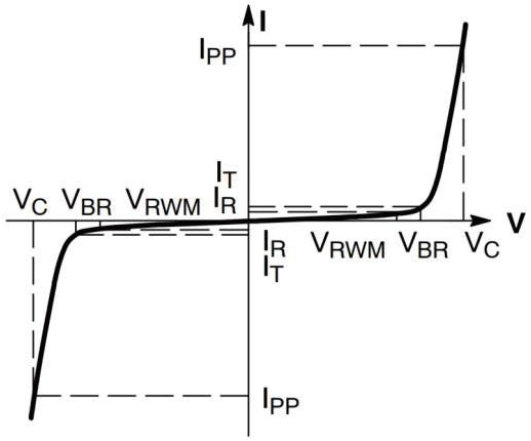
Absolute Ratings(Tamb = 25°C)

Parameter	Symbol	Value	Unit
Peak Pulse Power (tp = 8/20μs)	P_{PPM}	104	W
Maximum lead temperature for soldering during 10s	T_L	260	°C
Storage Temperature Range	T_{stg}	-55 to +150	°C
Operating Temperature Range	T_{OP}	-40 to +125	°C
Maximum junction temperature	T_j	150	°C
ESD voltage IEC 61000-4-2 (air discharge)	V_{ESD}	20	kV
ESD voltage IEC 61000-4-2 (contact discharge)	V_{ESD}	15	kV

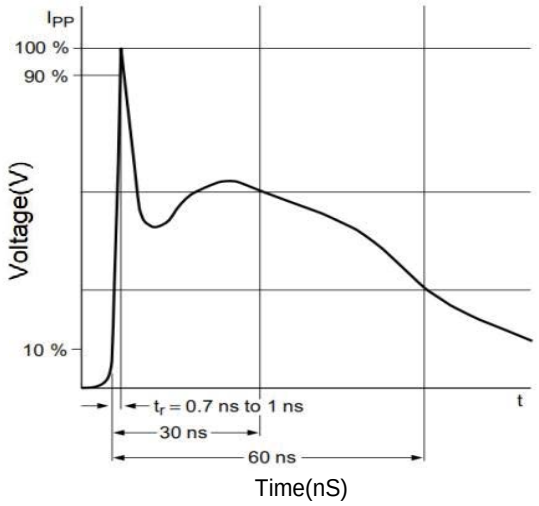
Electrical Characteristics

Parameter	Symbol	Min	Typ	Max	Unit	Condition
Reverse Working Voltage	V_{RWM}	--	--	7.0	V	
Breakdown Voltage	V_{BR}	7.6	8.2	9.0	V	I_T=1mA
Leakage Current ILeak	I_R	--	--	0.1	nA	V_{RWM}=7.0V
Clamping Voltage	V_C	--	10.0	12.0	V	I_{PP}=5A,Tp=8/20μs
Clamping Voltage	V_C	--	11.5	13.0	V	I_{PP}=8A,Tp=8/20μs
Junction Capacitance	C_J	--	18.0	--	pF	V_R=0V, f=1MHz

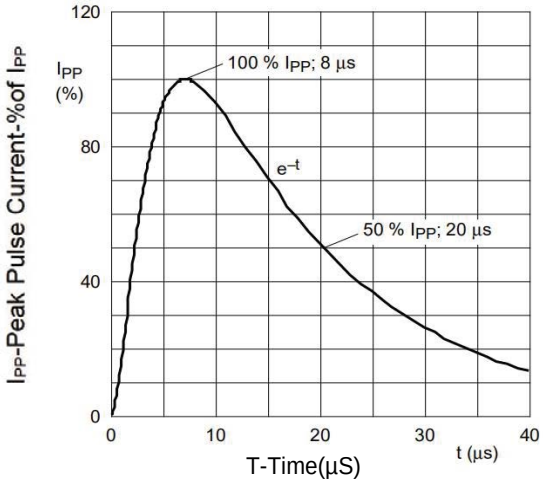
Symbol	Parameter
I_{PPM}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Working Peak Reverse Voltage
I_R	Reverse Leakage Current @ V_{RWM}
I_T	Test Current
V_{BR}	Breakdown Voltage @ I_T



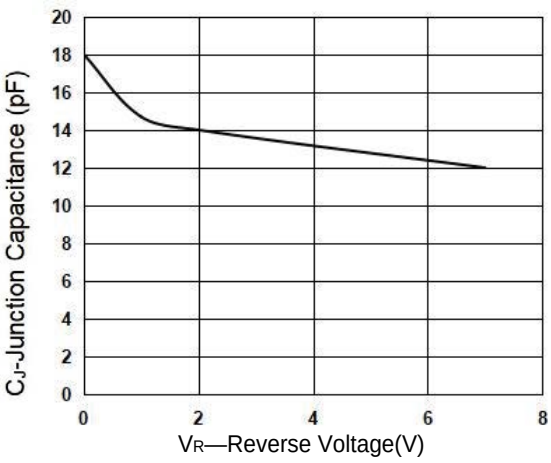
Typical Characteristics



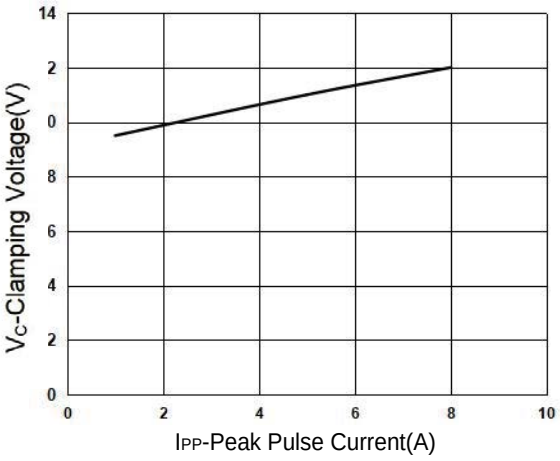
IEC61000−4−2 Pulse Waveform



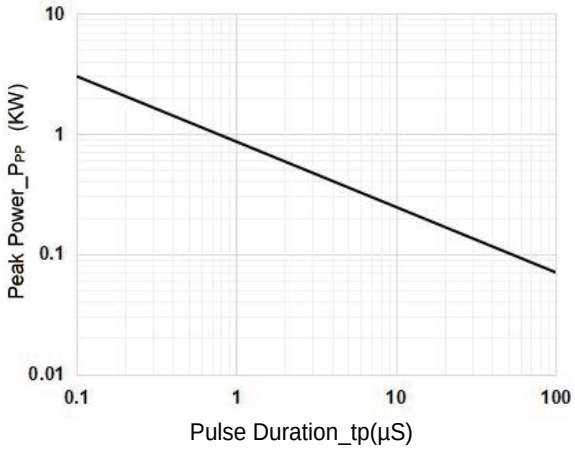
IEC61000−4−5 8X20µs Pulse Waveform



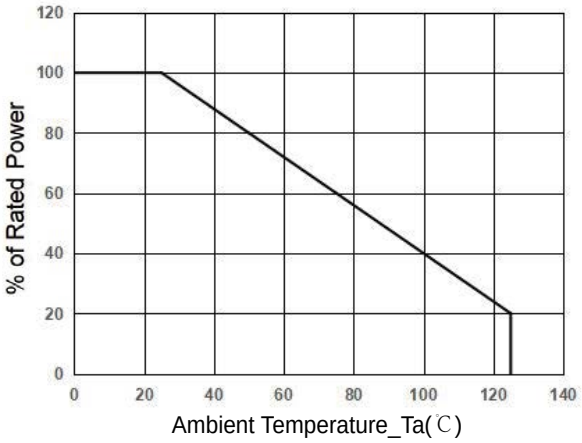
Junction Capacitance vs. Reverse Voltage



Clamping Voltage vs. Peak Pulse Current

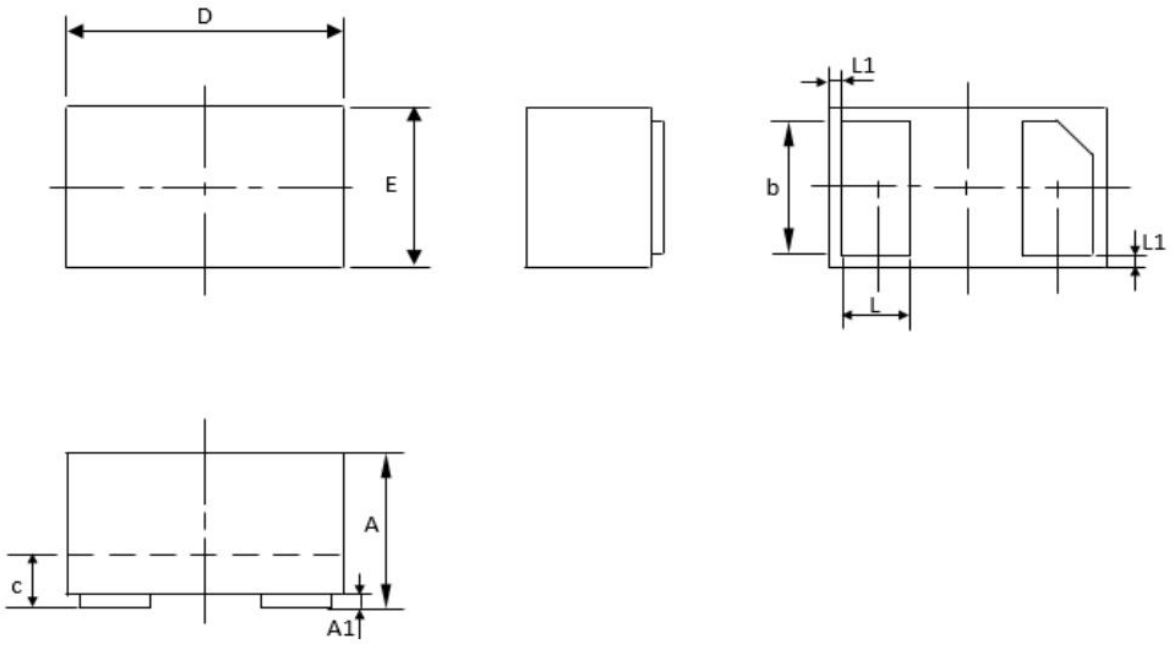


Peak Pulse Power vs. Pulse Time



Power Derating Curve

Outline And Dimensions



DFN1006-2L			
Dim	Min	Typ.	Max
A	0.46	0.48	0.50
A1	0	0.02	0.05
b	0.45	0.5	0.55
c	0.1	0.12	0.14
D	0.95	1.00	1.05
E	0.55	0.60	0.65
L	0.20	0.25	0.30
L1	0.035	0.05	0.065
h	0.07	0.12	0.17
All Dimensions in mm			

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